

DS90C032B

LVDS Quad CMOS Differential Line Receiver

General Description

TheDS90C032B is a quad CMOS differential line receiver designed for applications requiring ultra low power dissipation and high data rates. The device is designed to support data rates in excess of 155.5 Mbps (77.7 MHz) utilizing Low Voltage Differential Signaling (LVDS) technology.

TheDS90C032B accepts low voltage (350 mV) differential input signals and translates them to CMOS (TTL compatible) output levels. The receiver supports a TRI-STATE® function that may be used to multiplex outputs. The receiver also supports OPEN Failsafe and terminated (100 Ω) input Failsafe with the addition of external failsafe biasing. Receiver output will be HIGH for both Failsafe conditions.

The DS90C032Bprovides power-off high impedance LVDS inputs. This feature assures minimal loading effect on the LVDS bus lines when $V_{\rm CC}$ is not present.

The DS90C032Band companion line driver (DS90C031B) provide a new alternative to high power pseudo-ECL devices for high speed point-to-point interface applications.

Features

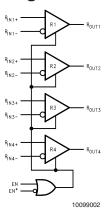
- >155.5 Mbps (77.7 MHz) switching rates
- Accepts small swing (350 mV) differential signal levels
- High Impedance LVDS inputs with power down
- Ultra low power dissipation
- 600 ps maximum differential skew (5V, 25°C)
- 6.0 ns maximum propagation delay
- Industrial operating temperature range
- Available in surface mount packaging (SOIC)
- Pin compatible with DS26C32A, MB570 (PECL) and 41LF (PECL)
- Supports OPEN and terminated input failsafe
- Conforms to ANSI/TIA/EIA-644 LVDS standard

Connection Diagram

Pint - 1 16 Vcc Rin1 - 2 15 Rin4 - 8 13 Rout1 Rin2 - 5 12 En* Rin2 - 6 11 Rin2 - 7 10 Rin3 - 8 9 Rin3 - 10099001

Order Number DS90C032BTM See NS Package Number M16A

Functional Diagram



Receiver Truth Table

ENABLES		INPUTS	OUTPUT	
EN	EN*	R _{IN+} - R _{IN-}	R _{OUT}	
L	Н	X	Z	
All other		$V_{ID} \ge 0.1V$	Н	
combinations				
of ENABLE		$V_{ID} \leq -0.1V$	L	
inputs				
		Failsafe OPEN	Н	
		or Terminated		

TRI-STATE® is a registered trademark of National Semiconductor Corporation.

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Supply Voltage (V_{CC}) -0.3V to +6VInput Voltage (R_{IN+}, R_{IN-}) -0.3V to +5.8V

Enable Input Voltage

(EN, EN*) -0.3V to $(V_{CC} + 0.3V)$ Output Voltage (R_{OUT}) -0.3V to $(V_{CC} + 0.3V)$

Maximum Package Power Dissipation @ +25°C

M Package 1025 mW 8.2 mW/°C above

Derate M Package +25°C

Storage Temperature Range -65°C to +150°C

Lead Temperature Range

Soldering (4 sec.) +260°C

Maximum Junction

+150°C Temperature

ESD Rating (Note 7) (HBM, 1.5 k Ω , 100 pF) (EIAJ, 0 Ω, 200 pF)

 $\geq 2kV$ ≥ 250V

Recommended Operating Conditions

Min Typ Max Units Supply Voltage +4.5 +5.0 +5.5 ٧

 (V_{CC})

Receiver Input GND ٧ 2.4

Voltage

Operating Free Air Temperature

 (T_A)

DS90C032BT -40 +25 +85 °C

Electrical Characteristics

Over Supply Voltage and Operating Temperature ranges, unless otherwise specified. (Notes 2, 3)

Symbol	Parameter	Conditions	Pin	Min	Тур	Max	Units
V_{TH}	Differential Input High Threshold	$V_{CM} = +1.2V$	R _{IN+} ,			+100	mV
V_{TL}	Differential Input Low Threshold		R _{IN-}	-100			mV
I _{IN}	Input Current	$V_{IN} = +2.4V$ $V_{CC} = 5.5V \text{ or } 0V$		-10	±1	+10	μΑ
		V _{IN} = 0V		-10	±1	+10	μΑ
V _{OH}	Output High Voltage	$I_{OH} = -0.4 \text{ mA}, V_{ID} = +200 \text{ mV}$	R _{OUT}	3.8	4.9		V
		$I_{OH} = -0.4$ mA, Input terminated		3.8	4.9		V
V _{OL}	Output Low Voltage	$I_{OL} = 2 \text{ mA}, V_{ID} = -200 \text{ mV}$			0.07	0.3	V
Ios	Output Short Circuit Current	Enabled, V _{OUT} = 0V (Note 8)		-15	-60	-100	mA
l _{oz}	Output TRI-STATE Current	Disabled, V _{OUT} = 0V or V _{CC}		-10	±1	+10	μΑ
V_{IH}	Input High Voltage		EN,	2.0			V
V_{IL}	Input Low Voltage		EN*			0.8	V
I _I	Input Current			-10	±1	+10	μΑ
V_{CL}	Input Clamp Voltage	$I_{CL} = -18 \text{ mA}$		-1.5	-0.8		V
I _{cc}	No Load Supply Current	EN, EN* = V _{CC} or GND, Inputs Open			3.5	10	mA
	Receivers Enabled	EN, EN* = 2.4 or 0.5, Inputs Open			3.7	11	mA
I _{CCZ}	No Load Supply Current	EN = GND, EN* = V _{CC} , Inputs Open			3.5	10	mA
	Receivers Disabled						

Switching Characteristics

 $V_{CC} = +5.0V$, $T_A = +25^{\circ}C$ (Notes 3, 4, 9)

Symbol	Parameter	Conditions	Min	Тур	Max	Units
t _{PHLD}	Differential Propagation Delay High to Low	$C_L = 5 pF$	1.5	3.40	5.0	ns
t _{PLHD}	Differential Propagation Delay Low to High	V _{ID} = 200 mV	1.5	3.48	5.0	ns
t _{SKD}	Differential Skew It _{PHLD} - t _{PLHD} I	(Figure 1 and Figure 2)	0	80	600	ps
t _{SK1}	Channel-to-Channel Skew (Note 5)		0	0.6	1.0	ns
t _{TLH}	Rise Time			0.5	2.0	ns
t _{THL}	Fall Time			0.5	2.0	ns
t _{PHZ}	Disable Time High to Z $R_{L} = 2 \ k\Omega$			10	15	ns
t _{PLZ}	Disable Time Low to Z $C_L = 10 \text{ pF}$			10	15	ns
t _{PZH}	Enable Time Z to High (Figure 3 and Figure 4)			4	10	ns
t _{PZL}	Enable Time Z to Low			4	10	ns

Switching Characteristics

 V_{CC} = +5.0V ± 10%, T_A = -40°C to +85°C (Notes 3, 4, 9)

Symbol	Parameter	Conditions	Min	Тур	Max	Units
t _{PHLD}	Differential Propagation Delay High to Low	$C_L = 5 pF$	1.0	3.40	6.0	ns
t _{PLHD}	Differential Propagation Delay Low to High	V _{ID} = 200 mV	1.0	3.48	6.0	ns
t _{SKD}	Differential Skew It _{PHLD} - t _{PLHD} I	(Figure 1 and Figure 2)	0	0.08	1.2	ns
t _{SK1}	Channel-to-Channel Skew (Note 5)		0	0.6	1.5	ns
t _{SK2}	Chip to Chip Skew (Note 6)				5.0	ns
t _{TLH}	Rise Time			0.5	2.5	ns
t _{THL}	Fall Time			0.5	2.5	ns
t _{PHZ}	Disable Time High to Z	$R_L = 2 k\Omega$		10	20	ns
t _{PLZ}	Disable Time Low to Z	C _L = 10 pF		10	20	ns
t _{PZH}	Enable Time Z to High	(Figure 3 and Figure 4)		4	15	ns
t _{PZL}	Enable Time Z to Low			4	15	ns

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" specifies conditions of device operation.

Note 2: Current into device pins is defined as positive. Current out of device pins is defined as negative. All voltages are referenced to ground unless otherwise specified

Note 3: All typicals are given for: $V_{CC} = +5.0V$, $T_A = +25^{\circ}C$.

Note 4: Generator waveform for all tests unless otherwise specified: f = 1 MHz, $Z_0 = 50\Omega$, t_r and t_f (0%–100%) ≤ 1 ns for R_{IN} and t_f and $t_f \leq 6$ ns for EN or EN*.

Note 5: Channel-to-Channel Skew is defined as the difference between the propagation delay of one channel and that of the others on the same chip with an event on the inputs

Note 6: Chip to Chip Skew is defined as the difference between the minimum and maximum specified differential propagation delays.

Note 7: ESD Rating:

HBM (1.5 k Ω , 100 pF) \geq 2kV

EIAJ (0 Ω , 200 pF) \geq 250V

Note 8: Output short circuit current (IoS) is specified as magnitude only, minus sign indicates direction only. Only one output should be shorted at a time, do not exceed maximum junction temperature specification.

Note 9: C_L includes probe and jig capacitance.

Parameter Measurement Information

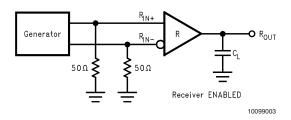


FIGURE 1. Receiver Propagation Delay and Transition Time Test Circuit

Parameter Measurement Information (Continued)

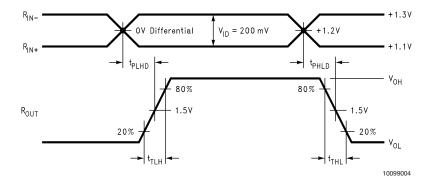
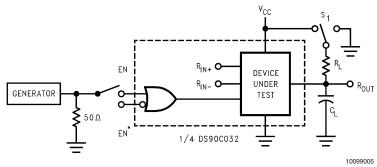


FIGURE 2. Receiver Propagation Delay and Transition Time Waveforms



 C_L includes load and test jig capacitance.

 $S_1 = V_{CC}$ for t_{PZL} and t_{PLZ} measurements.

 S_1 = GND for t_{PZH} and t_{PHZ} measurements.

FIGURE 3. Receiver TRI-STATE Delay Test Circuit

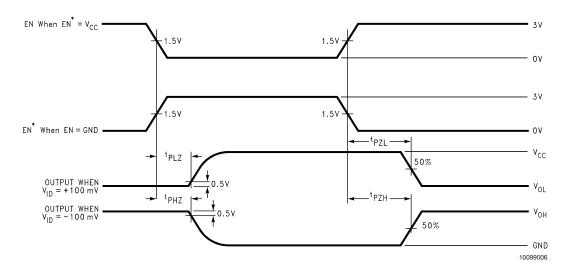


FIGURE 4. Receiver TRI-STATE Delay Waveforms

Typical Application

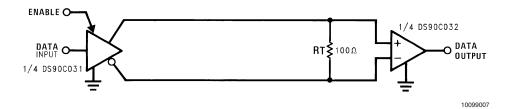


FIGURE 5. Point-to-Point Application

Applications Information

LVDS drivers and receivers are intended to be primarily used in an uncomplicated point-to-point configuration as is shown in Figure 5. This configuration provides a clean signaling environment for the quick edge rates of the drivers. The receiver is connected to the driver through a balanced media which may be a standard twisted pair cable, a parallel pair cable, or simply PCB traces. Typically the characteristic impedance of the media is in the range of 100Ω . A termination resistor of 100Ω should be selected to match the media, and is located as close to the receiver input pins as possible. The termination resistor converts the current sourced by the driver into a voltage that is detected by the receiver. Other configurations are possible such as a multi-receiver configuration, but the effects of a mid-stream connector(s), cable stub(s), and other impedance discontinuities as well as ground shifting, noise margin limits, and total termination loading must be taken into account.

TheDS90C032B differential line receiver is capable of detecting signals as low as 100 mV, over a ± 1 V common-mode range centered around +1.2V. This is related to the driver offset voltage which is typically +1.2V. The driven signal is centered around this voltage and may shift ± 1 V around this center point. The ± 1 V shifting may be the result of a ground potential difference between the driver's ground reference and the receiver's ground reference, the common-mode effects of coupled noise, or a combination of the two. Both receiver input pins should honor their specified operating input voltage range of 0V to +2.4V (measured from each pin to ground), exceeding these limits may turn on the ESD protection circuitry which will clamp the bus voltages.

RECEIVER FAILSAFE

The LVDS receiver is a high gain, high speed device that amplifies a small differential signal (20mV) to CMOS logic levels. Due to the high gain and tight threshold of the receiver, care should be taken to prevent noise from appearing as a valid signal.

The receiver's internal failsafe circuitry is designed to source/sink a small amount of current, providing failsafe protection (a stable known state of HIGH output voltage) for floating and terminated (100Ω) receiver inputs in low noise environment (differential noise < 10mV).

 Open Input Pins. TheDS90C032B is a quad receiver device, and if an application requires only 1, 2 or 3 receivers, the unused channel(s) inputs should be left OPEN. Do not tie unused receiver inputs to ground or any other voltages. The input is biased by internal high value pull up and pull down resistors to set the output to a HIGH state. This internal circuitry will guarantee a HIGH, stable output state for open inputs.

Terminated Input. TheDS90C032B requires external failsafe biasing for terminated input failsafe.

Terminated input failsafe is the case of a receiver that has a 100Ω termination across its inputs and the driver is in the following situations. Unplugged from the bus, or the driver output is in TRI-STATE or in power-off condition. The use of external biasing resistors provide a small bias to set the differential input voltage while the line is un-driven, and therefore the receiver output will be in HIGH state. If the driver is removed from the bus but the cable is still present and floating, the unplugged cable can become a floating antenna that can pick up noise. The LVDS receiver is designed to detect very small amplitude and width signals and recover them to standard logic levels. Thus, if the cable picks up more than 10mV of differential noise, the receiver may respond. To insure that any noise is seen as commonmode and not differential, a balanced interconnect and twisted pair cables is recommended, as they help to ensure that noise is coupled common to both lines and rejected by the receivers.

Operation in environment with greater than 10mV differential noise.

National recommends external failsafe biasing on its LVDS receivers for a number of system level and signal quality reasons. First, only an application that requires failsafe biasing needs to employ it. Second, the amount of failsafe biasing is now an application design parameter and can be custom tailored for the specific application. In applications in low noise environments, they may choose to use a very small bias if any. For applications with less balanced interconnects and/or in high noise environments they may choose to boost failsafe further. Nationals "LVDS Owner's Manual provides detailed calculations for selecting the proper failsafe biasing resistors. Third, the common-mode voltage is biased by the resistors during the un-driven state. This is selected to be close to the nominal driver offset voltage (V_{OS}). Thus when switching between driven and un-driven states, the common-mode modulation on the bus is held to a

For additional Failsafe Biasing information, please refer to Application Note AN-1194 for more detail.

The footprint of the DS90C032B is the same as the industry standard 26LS32 Quad Differential (RS-422) Receiver.

For additional LVDS application information, please refer to National's LVDS Owner's Manual available through National's website www.national.com/appinfo/lvds.

Pin Descriptions

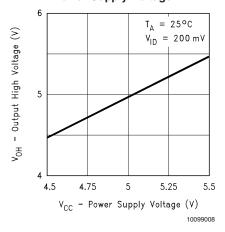
Pin No.	Name	Description
2, 6,	R _{IN+}	Non-inverting receiver input pin
10, 14		
1, 7, 9,	R_{IN-}	Inverting receiver input pin
15		
3, 5,	R _{OUT}	Receiver output pin
11, 13		
4	EN	Active high enable pin, OR-ed with
		EN*
12	EN*	Active low enable pin, OR-ed with EN
16	V _{CC}	Power supply pin, +5V ± 10%
8	GND	Ground pin

Ordering Information

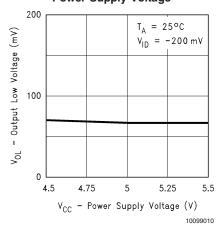
Operating Temperature	Package Type/ Number	Order Number
-40°C to +85°C	SOP/M16A	DS90C032BTM

Typical Performance Characteristics

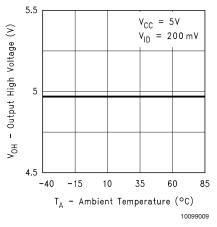
Output High Voltage vs Power Supply Voltage



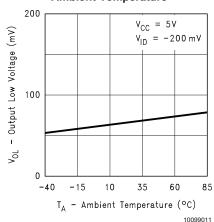
Output Low Voltage vs Power Supply Voltage



Output High Voltage vs Ambient Temperature

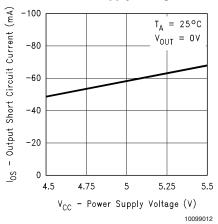


Output Low Voltage vs Ambient Temperature

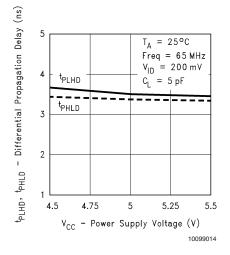


Typical Performance Characteristics (Continued)

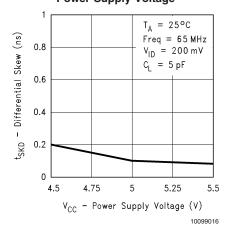
Output Short Circuit Current vs Power Supply Voltage



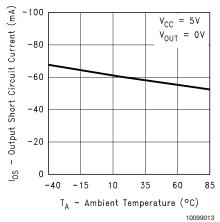
Differential Propagation Delay vs Power Supply Voltage



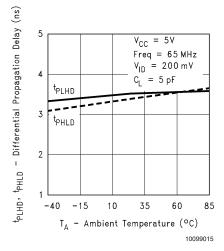
Differential Skew vs Power Supply Voltage



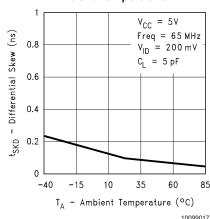
Output Short Circuit Current vs Ambient Temperature



Differential Propagation Delay vs Ambient Temperature

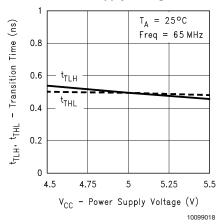


Differential Skew vs Ambient Temperature

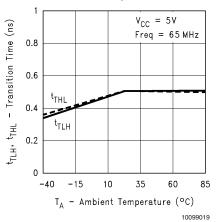


Typical Performance Characteristics (Continued)

Transition Time vs Power Supply Voltage

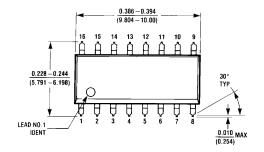


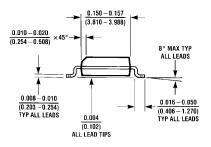
Transition Time vs Ambient Temperature

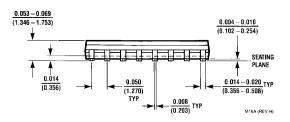


Physical Dimensions inches (millimeters)

unless otherwise noted







16-Lead (0.150" Wide) Molded Small Outline Package, JEDEC Order Number DS90C032BTM **NS Package Number M16A**

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Email: new.feedback@nsc.com Tel: 1-800-272-9959

www.national.com

National Semiconductor Europe Customer Support Center Fax: +49 (0) 180-530 85 86

Email: europe.support@nsc.com Deutsch Tel: +49 (0) 69 9508 6208 English Tel: +44 (0) 870 24 0 2171 Français Tel: +33 (0) 1 41 91 8790

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